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Expedited Procedure
Examining Group 2829
PATENT 740756-2101

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT application of:)

Art Unit: 2829

Shunpei YAMAZAKI et al.)

Examiner: Evan T. PERT

Application No.: 09/502,675)

Filed: February 11, 2000)

For: SEMICONDUCTOR DEVICE AND)
METHOD OF MANUFACTURING)
THEREFOR)

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AMENDMENT AFTER FINAL

Commissioner for Patents
Washington, D.C. 20231

Dear Sir:

In response to the Examiner's Final Office Action mailed April 1, 2002, the period for responding having been extended two (2) months, please consider the following amendments and remarks in connection with the above-identified application.

IN THE CLAIMS:

Please cancel claim 2 without prejudice or disclaimer to the subject matter disclosed therein.

Please amend claims 1, 9, 18 and 27 as follows.

1. (Twice Amended) A semiconductor device comprising a driver circuit and a pixel section over a substrate, wherein:

a) said driver circuit includes:

a first thin film transistor comprising:

a channel forming region and a third impurity region having n-type conductivity, wherein the channel forming region and the third impurity region are overlapped with a gate electrode;
and